

L Number	Hits	Search Text	DB	Time stamp
1	10	US-4863560-\$.DID. OR US-5338400-\$.DID. OR US-5611006-\$.DID. OR US-5911021-\$.DID. OR US-6187515-\$.DID.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/10 10:36
2	0	(optic\$ near crystal\$ near substrate\$) and (anisotrop\$ near etch\$ near groove\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/10 10:37
3	3	(optic\$ near crystal\$ near substrate\$) and (anisotrop\$ near etch\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/10 10:39
4	1	dry near pit near groove\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/10 10:40
5	410	anisotrop\$ near etch\$ near groove\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/10 10:41
6	138	(anisotrop\$ near etch\$ near groove\$) and optic\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/10 10:44
7	3	(anisotrop\$ near etch\$ near groove\$) and optic\$ and (dry near pit)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/10 10:45
8	172	(anisotrop\$ near etch\$ near groove\$) and (silicon\$ near substrate\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/10 10:48